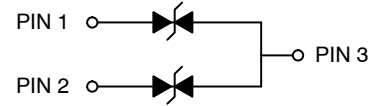


The ESDONCAN1L has been designed to protect the CAN transceiver from ESD and other harmful transient voltage events. This device provides bidirectional protection for each data line with a single compact SOT-23 package, giving the system designer a low cost option for improving system reliability and meeting stringent EMI requirements.



Features

- 200 W Peak Power Dissipation per Line (8 x 20 sec Waveform)
- Diode Capacitance Matching
- Low Reverse Leakage Current (< 100 nA)
- Low Capacitance High-Speed FlexRay Data Rates
- IEC Compatibility: – IEC 61000-4-2 (ESD): Level 4
 - IEC 61000-4-4 (EFT): 50 A – 5/50 ns
 - IEC 61000-4-5 (Lighting) 3.0 A (8/20 s)
- ISO 7637-1, Nonrepetitive EMI Surge Pulse 2, 8.0 A (1 x 50 s)
- ISO 7637-3, Repetitive Electrical Fast Transient (EFT) EMI Surge Pulses, 50 A (5 x 50 ns)
- Flammability Rating UL 94 V-0
- These are Pb-Free Devices

Typical Applications

- Industrial
 - ◆ Smart Distribution Systems (SDS)
 - ◆ DeviceNet

MAXIMUM RATINGS (T_J = 25°C, unless otherwise specified)

Symbol	Rating	Value	Unit
PPK	Peak Power Dissipation, 8 x 20 μs Double Exponential Waveform (Note 1)	200	W
T _J	Operating Junction Temperature Range	-55 to 150	°C
T _J	Storage Temperature Range	-55 to 150	°C
T _L	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body Model (HBM)	8.0	kV
	Machine Model (MM)	400	V
	IEC 61000-4-2 Specification (Contact)	23	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Non-repetitive current pulse per Figure 1.

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{RWM}	Reverse Working Voltage	(Note 2)	24	-	-	V
V_{BR}	Breakdown Voltage	$I_T = 1 \text{ mA}$ (Note 3)	26.2	-	32	V
I_R	Reverse Leakage Current	$V_{RWM} = 24 \text{ V}$	-	15	100	nA
V_C	Clamping Voltage	$I_{PP} = 1 \text{ A}$ ($8 \times 20 \mu\text{s}$ Waveform) (Note 4)	-	33.4	36.6	V
V_C	Clamping Voltage	$I_{PP} = 3 \text{ A}$ ($8 \times 20 \mu\text{s}$ Waveform) (Note 4)	-	44	50	V
I_{PP}	Maximum Peak Pulse Current	$8 \times 20 \mu\text{s}$ Waveform (Note 4)	-	-	3.0	A
C_J	Capacitance	$V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$ (Line to GND)	-	-	10	pF
ΔC	Diode Capacitance Matching	$V_R = 0 \text{ V}$, 5 MHz (Note 5)	-	0.26	2	%

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- Surge protection devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.
- V_{BR} is measured at pulse test current I_T .
- Pulse waveform per Figure 1.
- ΔC is the percentage difference between C_J of lines 1 and 2 measured according to the test conditions given in the electrical characteristics table.

TYPICAL PERFORMANCE CURVES

($T_J = 25^\circ\text{C}$ unless otherwise noted)

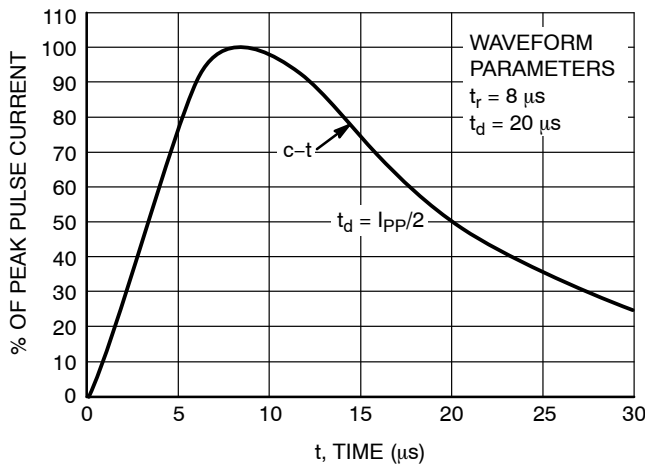


Figure 1. Pulse Waveform, $8 \times 20 \mu\text{s}$

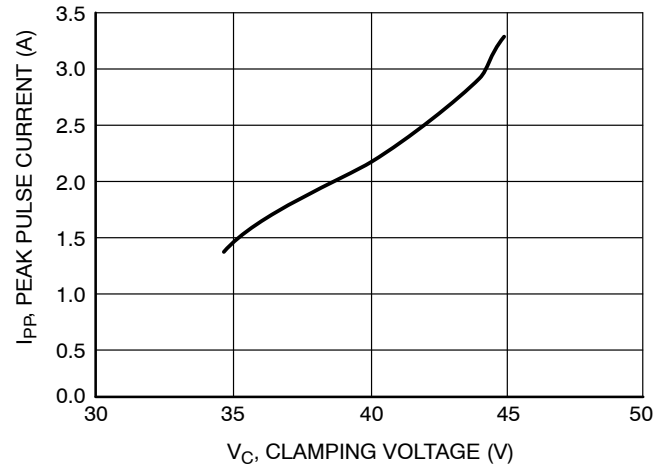


Figure 2. Clamping Voltage vs Peak Pulse Current

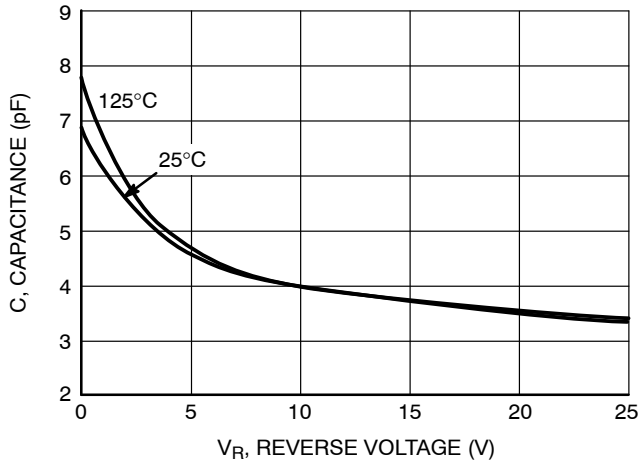


Figure 3. Typical Junction Capacitance vs Reverse Voltage

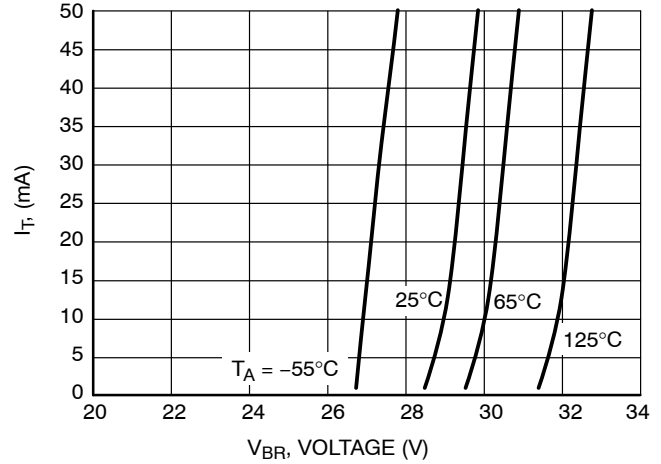


Figure 4. V_{BR} versus I_T Characteristics

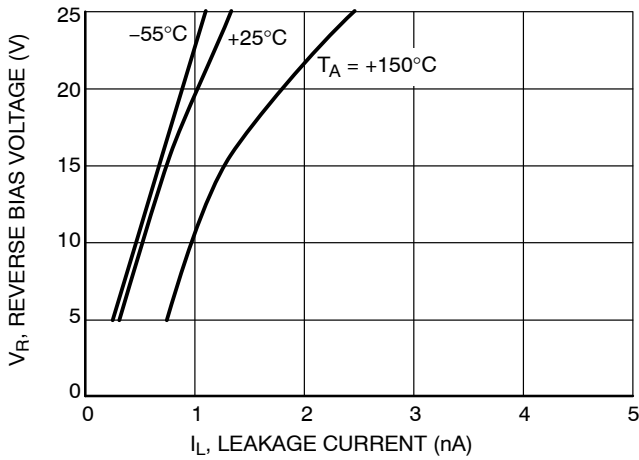


Figure 5. I_R versus Temperature Characteristics

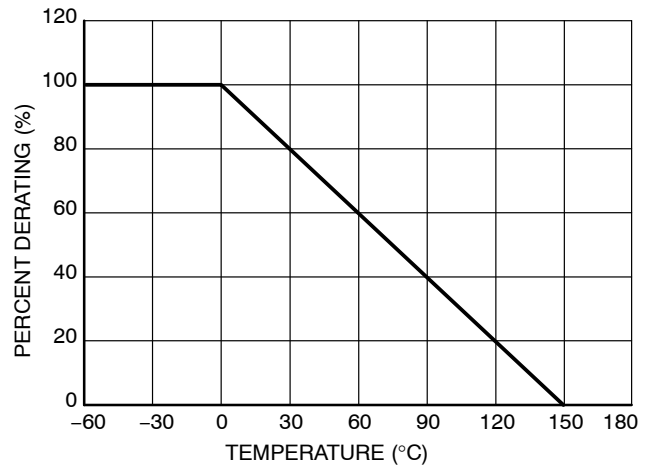
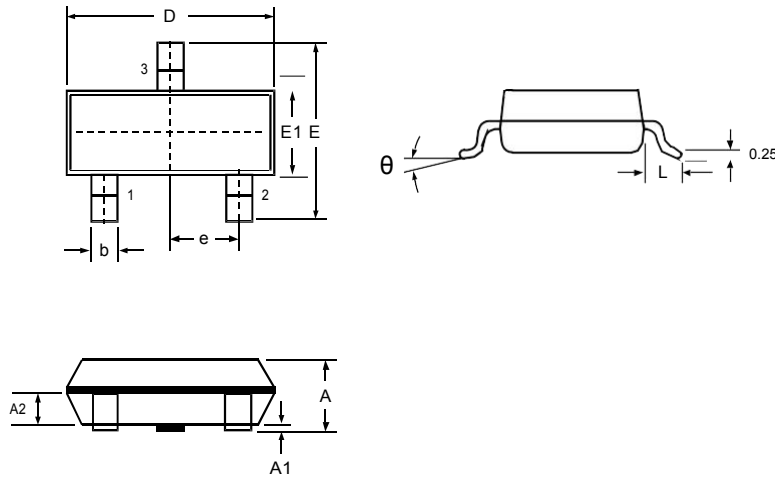


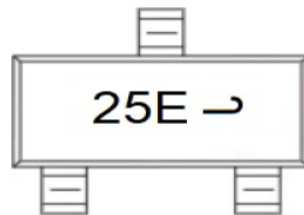
Figure 6. Temperature Power Dissipation Derating

Outline Drawing – SOT-23



SYMBOL	DIMENSIONS			
	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
D	2.800	3.000	0.110	0.118
b	0.300	0.500	0.012	0.020
E	2.250	2.550	0.089	0.100
E1	1.200	1.400	0.047	0.055
e	0.950 BSC		0.037 BSC	
L	0.500	0.675	0.020	0.027
θ	0	8°	0	8°

Marking



Ordering information

Order code	Package	Baseqty	Delivery mode
UMW ESDONCAN1LT1G	SOT-23	3000	Tape and reel

单击下面可查看定价，库存，交付和生命周期等信息

[>>UMW\(友台半导体\)](#)